

PJQ4546VP-AU

40V N-Channel Enhancement Mode MOSFET

Voltage	40 V	Current	61 A
----------------	-------------	----------------	-------------

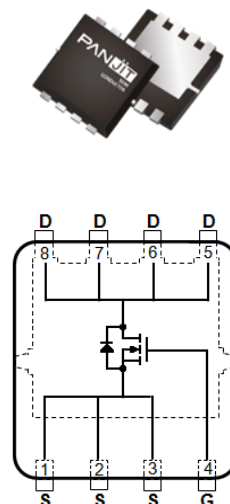
Features

- $R_{DS(ON)}$, $V_{GS}@10V$, $I_D@15A < 6.3m\Omega$
- $R_{DS(ON)}$, $V_{GS}@7V$, $I_D@10A < 7.7m\Omega$
- Excellent FOM
- Standard Level Drive
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : DFN3333-8L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.03 grams

DFN3333-8L



Maximum Ratings and Thermal Characteristics ($T_A=25^\circ C$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V_{DS}	40	V
Gate-Source Voltage		V_{GS}	± 20	
Continuous Drain Current ^(Note 3)	$T_C=25^\circ C$	I_D	61	A
	$T_C=100^\circ C$		43	
Pulsed Drain Current ^(Note 1)	$T_C=25^\circ C$	I_{DM}	244	
Power Dissipation	$T_C=25^\circ C$	P_D	42	W
	$T_C=100^\circ C$		21	
Continuous Drain Current ^(Note 4)	$T_A=25^\circ C$	I_D	15	A
	$T_A=70^\circ C$		12.4	
Power Dissipation	$T_A=25^\circ C$	P_D	2.5	W
	$T_A=70^\circ C$		1.8	
Single Pulse Avalanche Energy ^(Note 5)		E_{AS}	85	mJ
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55~175	$^\circ C$
Thermal Resistance ^(Note 4)	Junction to Case	$R_{\theta JC}$	3.6	$^\circ C/W$
	Junction to Ambient	$R_{\theta JA}$	60	



PJQ4546VP-AU

Electrical Characteristics (T_A=25°C unless otherwise noted)

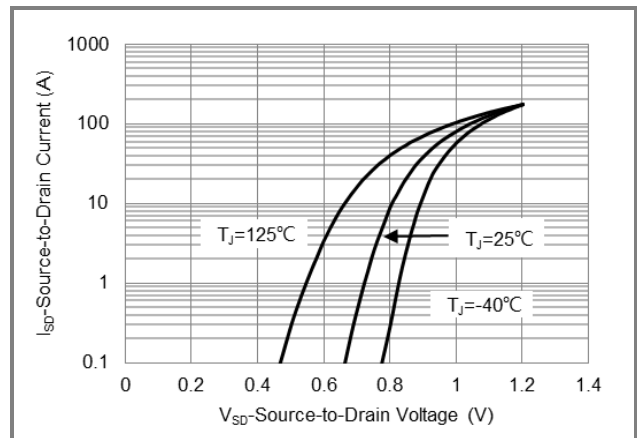
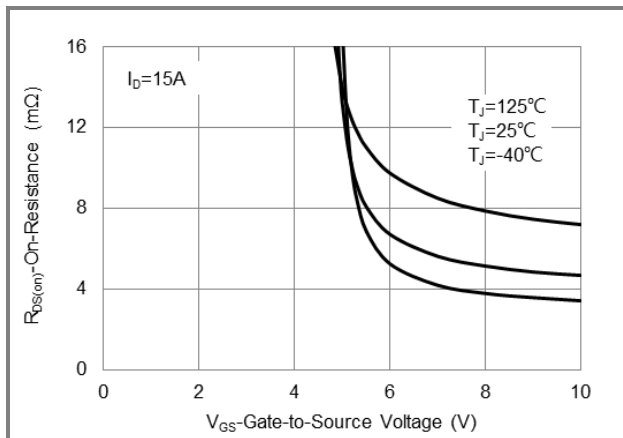
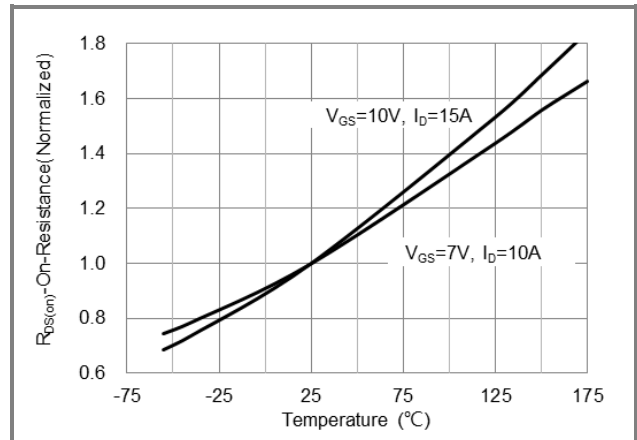
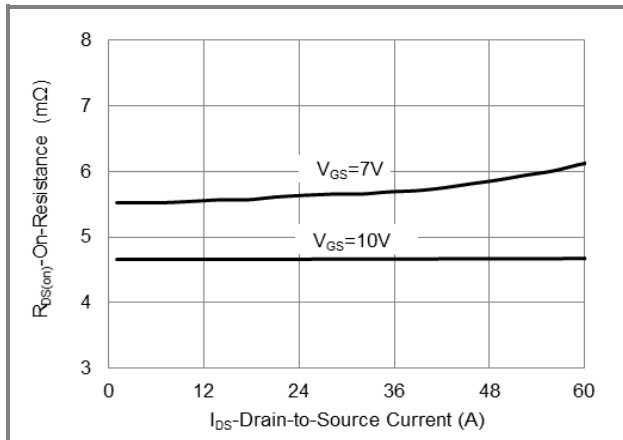
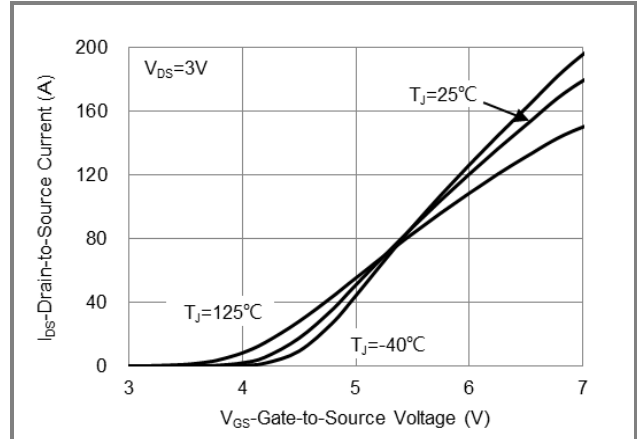
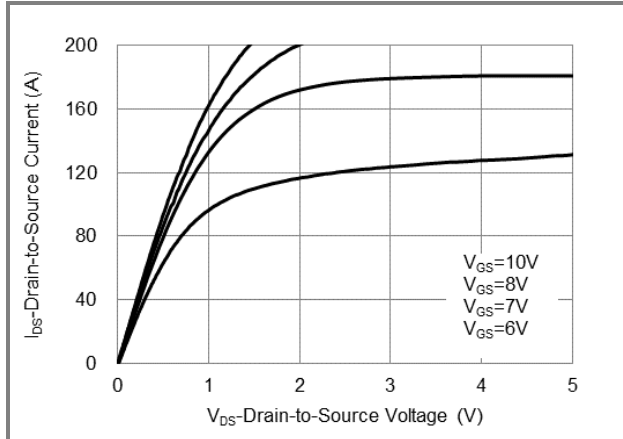
PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	40	-	-	V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =50uA	2	2.8	3.5	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V, I _D =15A	-	5	6.3	mΩ
		V _{GS} =7V, I _D =10A	-	5.9	7.7	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =40V, V _{GS} =0V	-	-	1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V	-	-	±100	nA
Dynamic ^(Note 6)						
Total Gate Charge	Q _g	V _{DS} =32V, I _D =15A, V _{GS} =10V ^(Note 2,3)	-	23	-	nC
Gate-Source Charge	Q _{gs}		-	5	-	
Gate-Drain Charge	Q _{gd}		-	6	-	
Input Capacitance	C _{iss}	V _{DS} =25V, V _{GS} =0V, f=1MHZ	-	1283	-	pF
Output Capacitance	C _{oss}		-	252	-	
Reverse Transfer Capacitance	C _{rss}		-	45	-	
Gate resistance	R _g	f=1MHZ	-	0.8	-	Ω
Turn-On Delay Time	td _(on)	V _{DS} =32V, I _D =15A, V _{GS} =10V, R _G =3Ω ^(Note 2,3)	-	17	-	ns
Turn-On Rise Time	tr		-	79	-	
Turn-Off Delay Time	td _(off)		-	37	-	
Turn-Off Fall Time	tf		-	23	-	
Drain-Source Diode						
Diode Forward Current	I _S	T _C =25 ^o C	-	-	61	A
Pulsed Diode Forward Current	I _{SM}		-	-	244	
Diode Forward Voltage	V _{SD}	I _S =20A, V _{GS} =0V	-	0.85	1.3	V
Reverse Recovery Time	T _{rr}	V _{GS} =0V, I _S =20A	-	43	-	ns
Reverse Recovery Charge	Q _{rr}	dI _S /dt=100A/us	-	34	-	nC

NOTES :

1. Pulse width≤100us, Duty cycle≤2%.
2. Essentially independent of operating temperature typical characteristics.
3. Chip capability with an R_{θJC}=3.6°C/W.
4. R_{θJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
5. The test condition is L=0.5mH, I_{AS}=18A, V_{DD}=30V, V_{GS}=10V, Starting T_J=25°C.
6. Guaranteed by design, not subject to production testing.

PJQ4546VP-AU

TYPICAL CHARACTERISTIC CURVES



PJQ4546VP-AU

TYPICAL CHARACTERISTIC CURVES

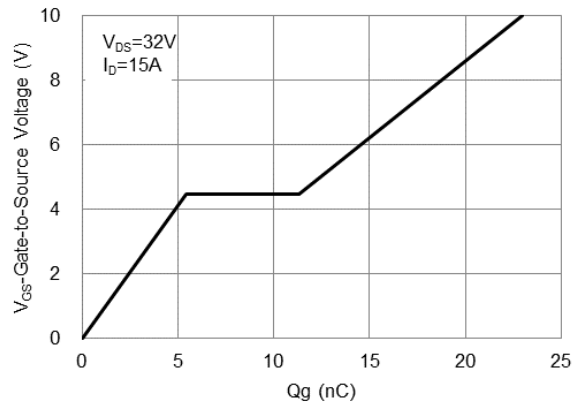


Fig.7 Gate-Charge Characteristics

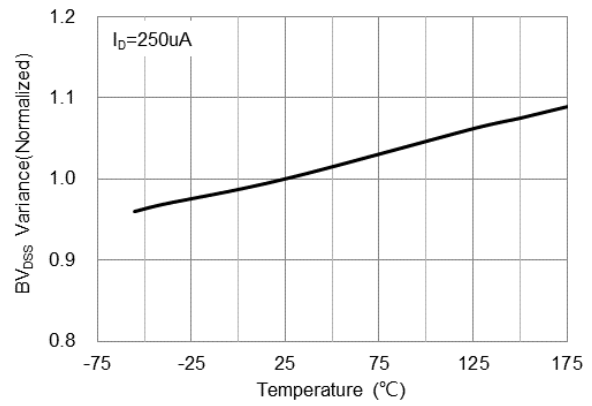


Fig.8 Breakdown Voltage Variation vs. Temperature

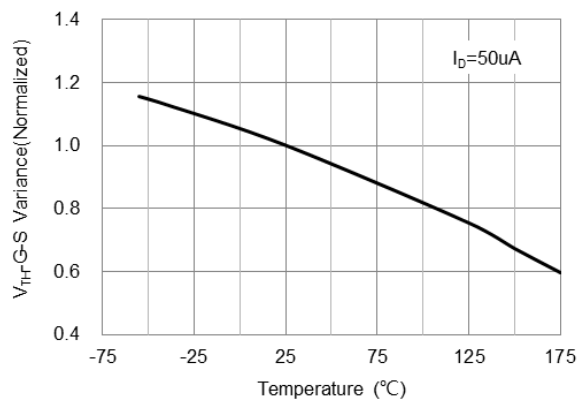


Fig.9 Threshold Voltage Variation with Temperature

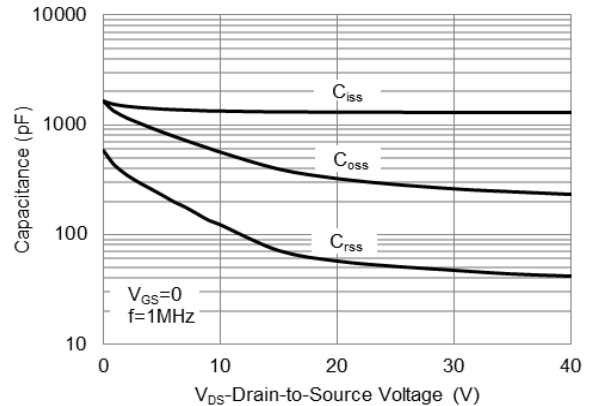


Fig.10 Capacitance vs. Drain-Source Voltage

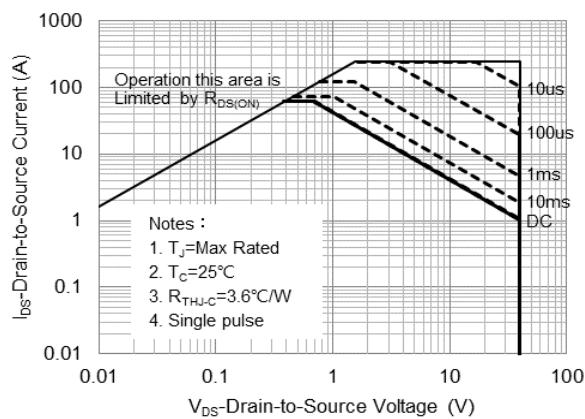


Fig.11 Maximum Safe Operating Area

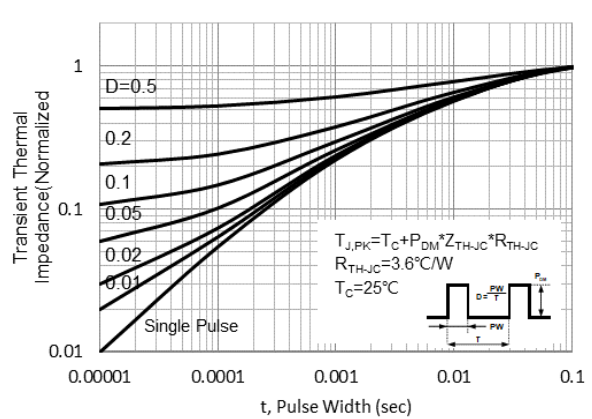


Fig.12 Normalized Transient Thermal Impedance



PJQ4546VP-AU

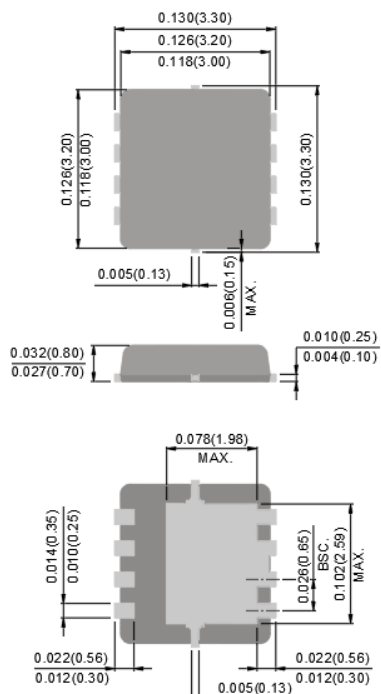
Part No. Packing Code Version

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJQ4546VP-AU_R2_002A1	DFN3333-8L	5K pcs / 13" reel	546V	Halogen free RoHS compliant

Packaging Information & Mounting Pad Layout

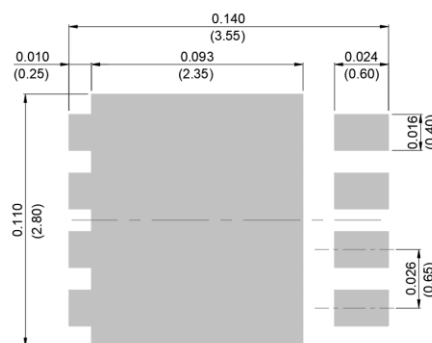
DFN3333-8L Dimension

Unit: inch(mm)



DFN3333-8L Pad Layout

Unit: inch(mm)





PJQ4546VP-AU

Disclaimer

- Reproducing and modifying information of the document is prohibited without permission from Panjit International Inc..
- Panjit International Inc. reserves the rights to make changes of the content herein the document anytime without notification. Please refer to our website for the latest document.
- Panjit International Inc. disclaims any and all liability arising out of the application or use of any product including damages incidentally and consequentially occurred.
- Panjit International Inc. does not assume any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.
- Applications shown on the herein document are examples of standard use and operation. Customers are responsible in comprehending the suitable use in particular applications. Panjit International Inc. makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.
- The products shown herein are not designed and authorized for equipments relating to human life and for any applications concerning life-saving or life-sustaining, such as medical instruments, aerospace machinery et cetera. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Panjit International Inc. for any damages resulting from such improper use or sale.
- Since Panjit uses lot number as the tracking base, please provide the lot number for tracking when complaining.